

# Large-Area CdTe Detector for X-ray Imaging and Overcoming Crystal Imperfections in CdTe Sensors

Zuzana Melnikova, Katerina Sykorova, Martin Konecny, Eliska Soharova and Jan Jakubek

ADVACAM s.r.o., U Pergamenky 12, 170 00 Prague 7, Czech Republic

International Workshop  
26th iWoRiD  
on Radiation Imaging Detectors



Funded by  
the European Union

Programme **Trend**

T A  
C R

- > X-ray imaging with single-photon counting detectors
- > Medipix-family detector and its key characteristics
- > Large-Area CdTe Detector
  - > Introduction + Parameters
  - > Large-Area X-ray Imaging
- > Detection stability improvement
  - > Hardware approach = Bias pulsing technique
  - > Software approach = AFF correction



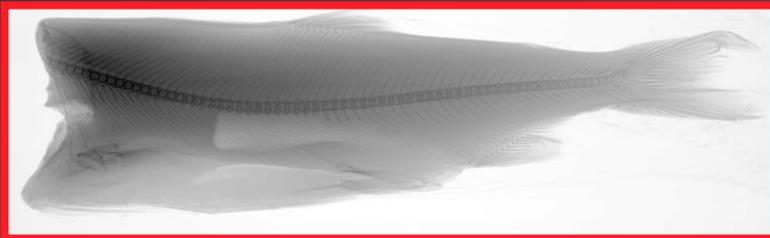
# X-RAY IMAGING RADIOGRAPHY WITH SINGLE-PHOTON COUNTING DETECTORS

## > Imaging parameters

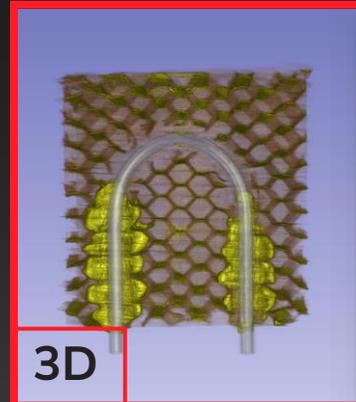
- > Photon counting => ultra high contrast
- > High spatial resolution
- > Ultra high dynamic range
- > High signal-to-noise ratio
- > Multichannel => material sensitivity



Excellent imaging properties!

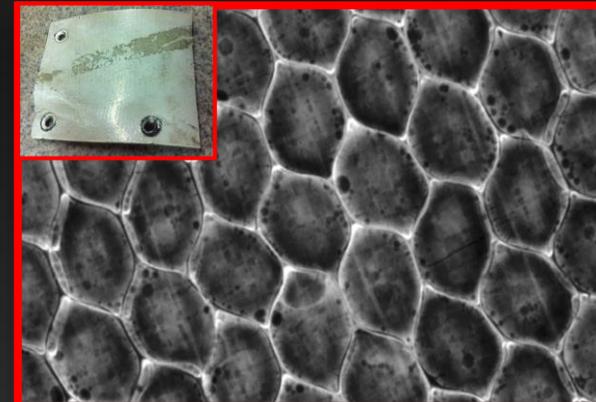


Food safety

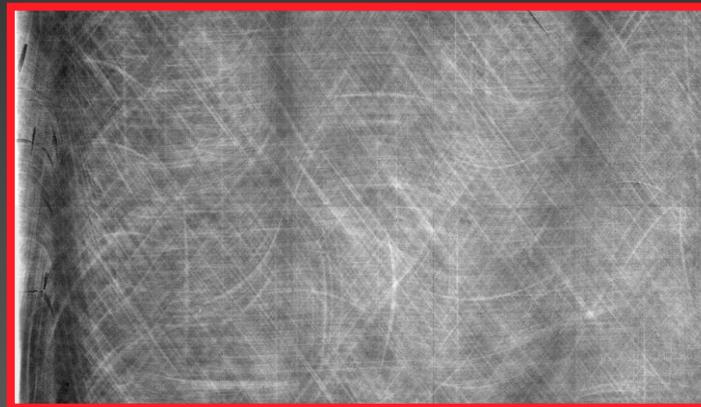


3D

NDT: Composite defectoscopy



Medicine



NDT: Detection of fiber undulations



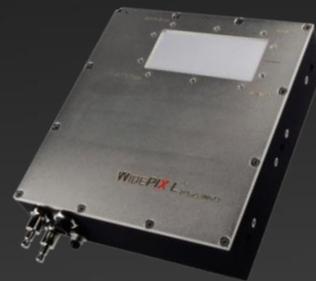
Paintings



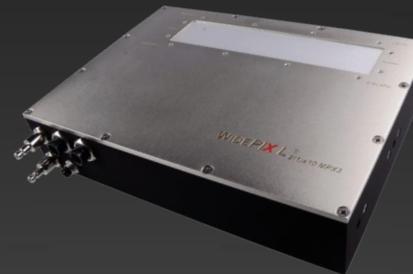
# MEDIPIX-FAMILY DETECTORS FOR X-RAY IMAGING

- > Technology based on CERN CMOS chips developed within MEDIPIX consortia.
- > **Very high signal to noise ratio**
- > Single photon counting
- > Direct conversion:  
**COUNT & ENERGY**
- > Signal is digital => very high speed
- > High resolution: sub 55  $\mu\text{m}$
- > Ultra high dynamic range
- > **Energy sensitive imaging**
- > Continuous operating modes for zero  
deadtime scanning implemented in hardware.

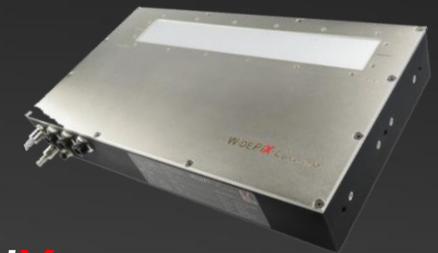
WIDEPIX L<sub>1X5</sub>



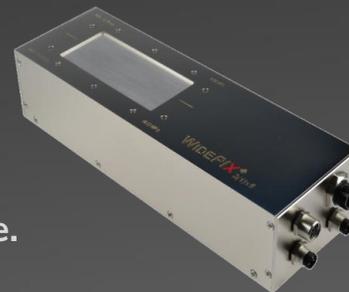
WIDEPIX L<sub>1X10</sub>



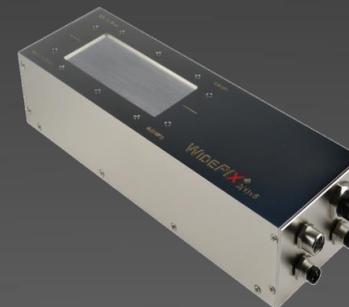
WIDEPIX L<sub>1X15</sub>



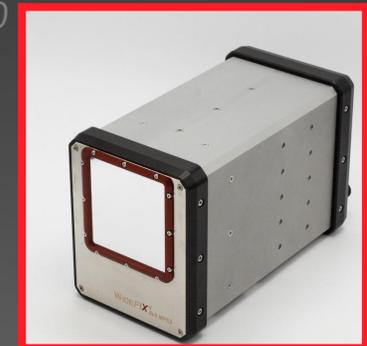
WIDEPIX<sub>1X5</sub>



WIDEPIX<sub>2X5</sub>



WIDEPIX<sub>5X5</sub>  
1280x1280



# KEY FEATURES OF THE WIDEPIX 5x5 MPX3

## > Sensor Configuration

> 5x5 array of Medipix3 chips (70 x 70 mm, 1.6 Mpixels) => ideal for imaging large areas.

## > Sensor Material and Thickness

> CdTe 1000  $\mu\text{m}$ .

## > Readout Speed = Frame Rate

> Capable of capturing up to 170 frames per second (fps).

## > Data Streaming

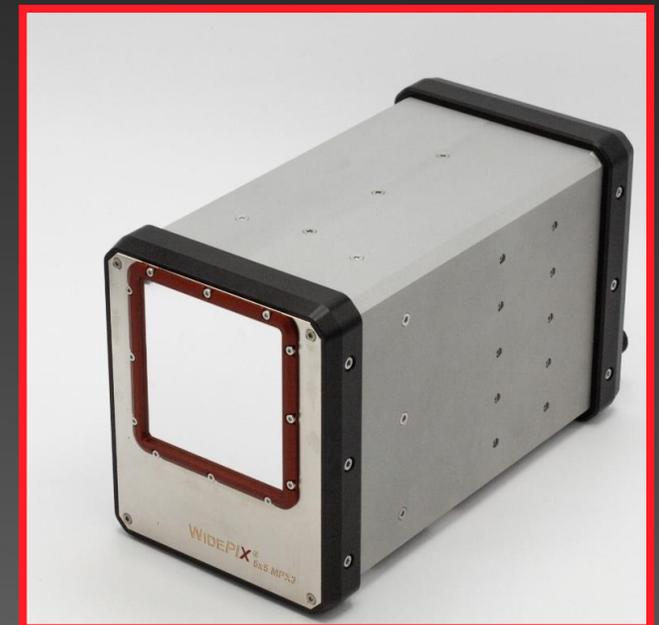
> Designed for high-speed data transmission (3.3 Gbit/s).

## > Dynamic Range

> Offers outstanding dynamic range, making it effective in imaging scenarios with both low and high signal intensities.

## DIMENSIONS and CONNECTIVITY

Dimensions:	139.5 x 119 x 227.2 mm
Weight:	4910 g
Connectivity:	5xEthernet
Software:	Pixet Pro

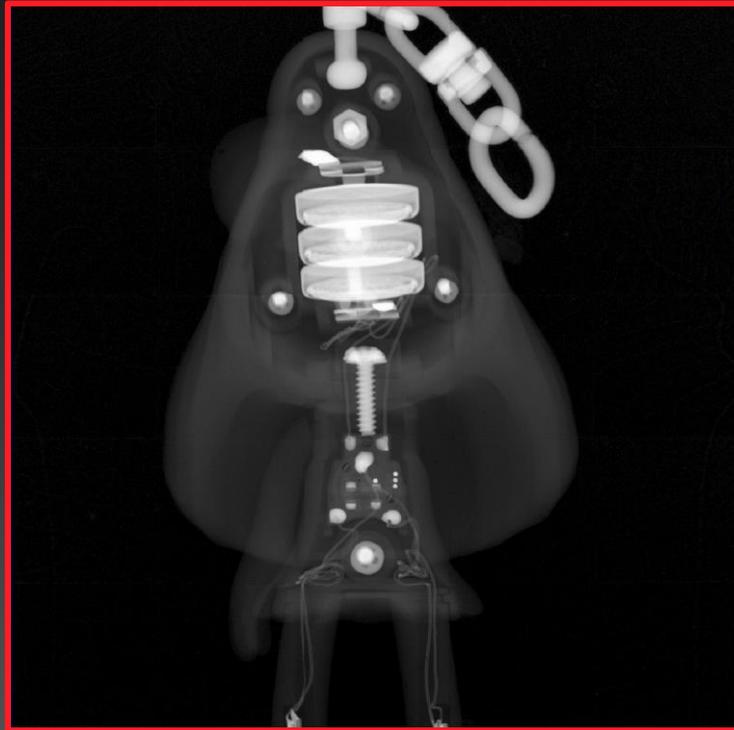


# MULTICHANNEL „COLOR“ RADIOGRAPHS ADVACAM Imaging the Unseen

Can you take a picture?



Standard X-ray



Material sensitive X-ray



Illustration of multichannel “color” radiographs where different materials are identified and imaged in different colors.

# APPLICATIONS SUITABILITY OF WIDEPPIX 5X5 MPX3

## > Medical imaging

- > more precise differentiation of soft tissues,
- > suppression of false positive effects

## > Non-destructive testing @ high energies:

- > thick, dense samples, like:
  - > batteries,
  - > engines of cars,
  - > basins in nuclear power plants, pipes for oil/gas...

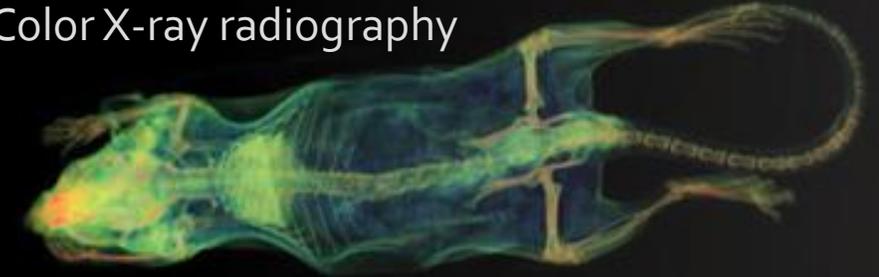
## > XRD

- > Compatible with X-ray imaging modalities due to Medipix-based detection

## > Research and other potential applications

- > e.g., space missions, high-energy physics.

Color X-ray radiography



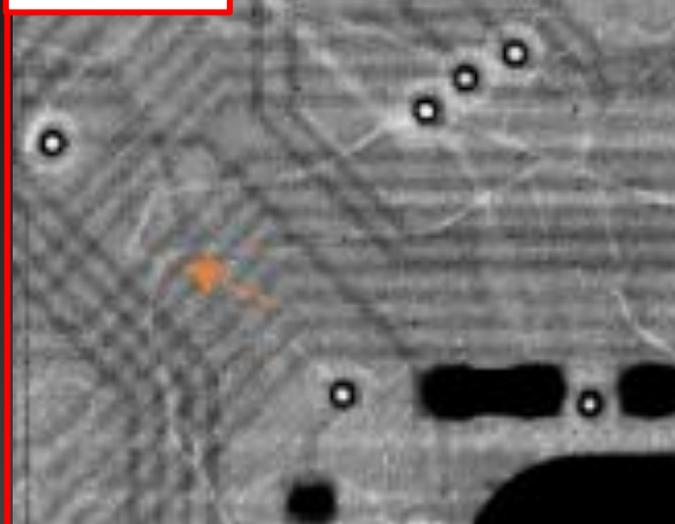
## > Advantages

- > High atomic numbers of components
- > High detection efficiency
- > Wide band gap ( $\sim 1.45$  eV)  $\Rightarrow$  no cooling
- > High density ( $\sim 5.85$  g/cm<sup>3</sup>)
- > Typical detectable energy range for X-rays: 5-500 keV

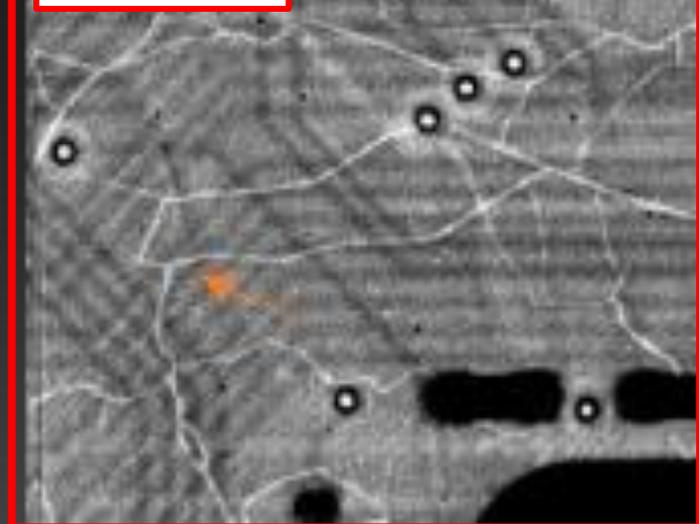
## > Disadvantages

- > Material defects and inhomogeneity
- > Low mobility  $\Rightarrow$  lifetime product ( $\mu\tau$ ) of charge carriers
- > Polarization at high intensity
- > Poor detection stability
- > SNR = 300-500

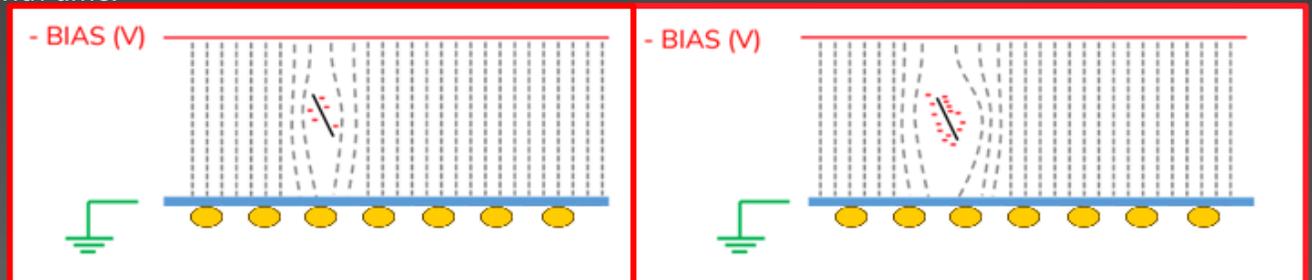
after 1 sec



after 10 min



X-ray radiography of the printed circuit board shows artifacts caused by defects in the CdTe sensor crystal at 1 s (left) and 10 minutes (right). "Vein-like" artifacts, indicated by an arrow, are worsening with time.



# WHAT CAN WE DO WITH IMPERFECTIONS?

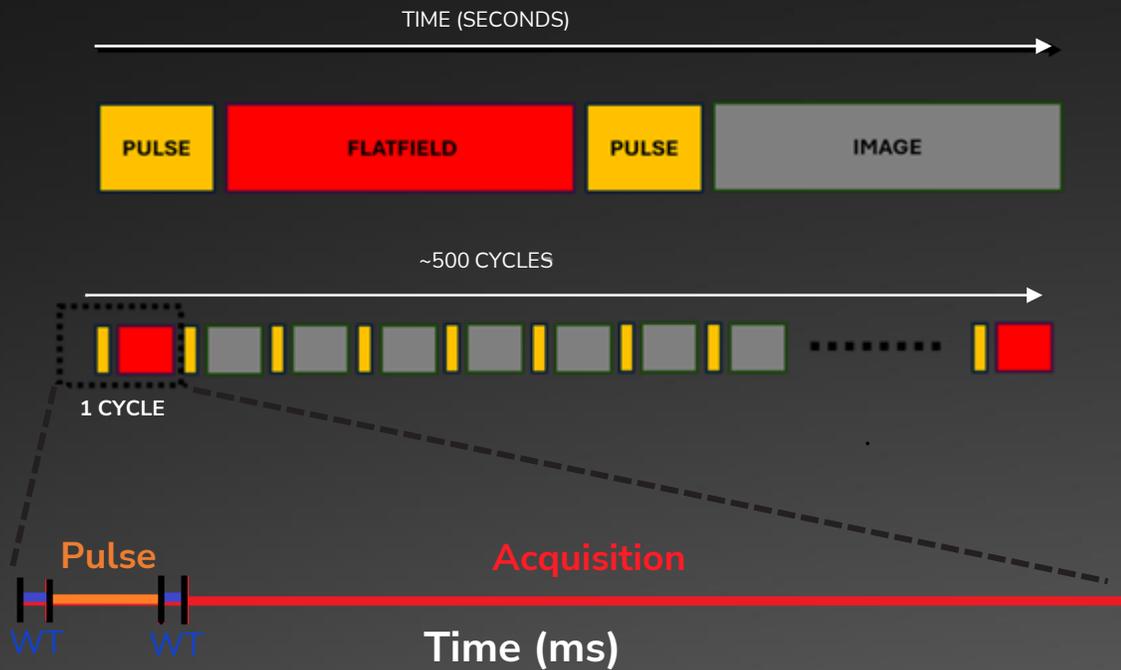
## > Solution approaches

Hardware = **PULSED BIAS VOLTAGE SWITCHING** TECHNIQUE

Software = **ADAPTIVE FLAT FIELD** (AFF) CORRECTION

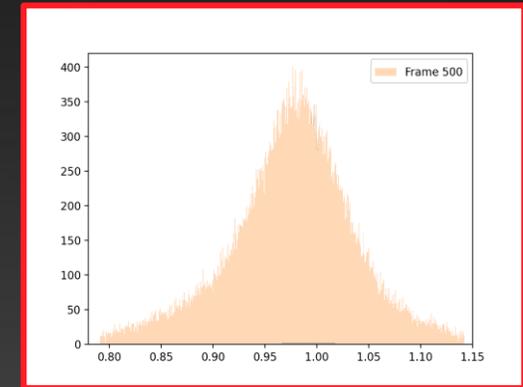
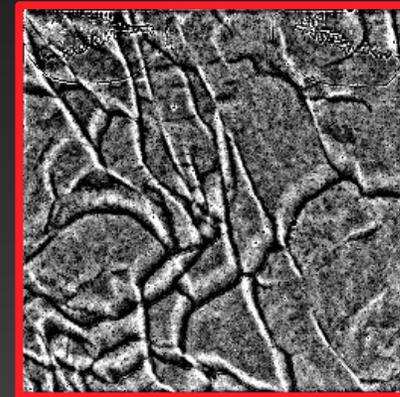
# PULSED BIAS VOLTAGE SWITCHING TECHNIQUE

**Principle:** Reset the accumulated space charge to a stable “fixed state” before each image.

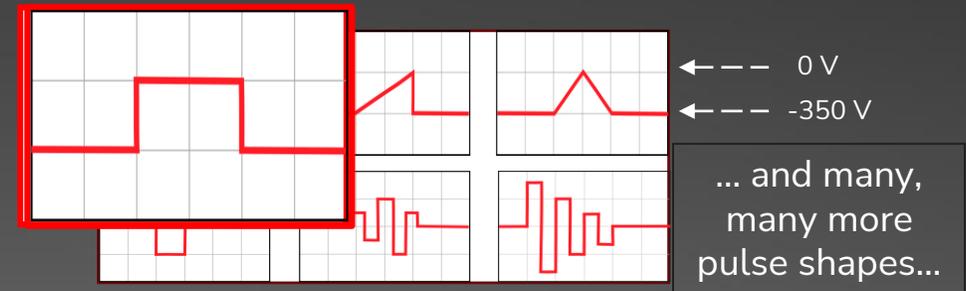


WT – waiting time

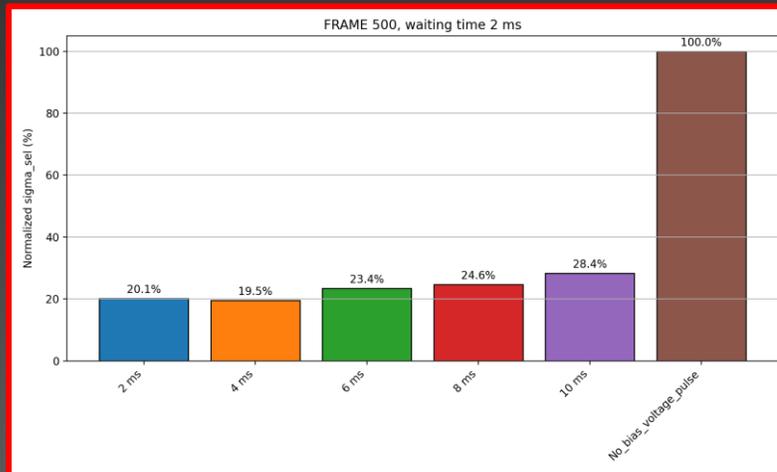
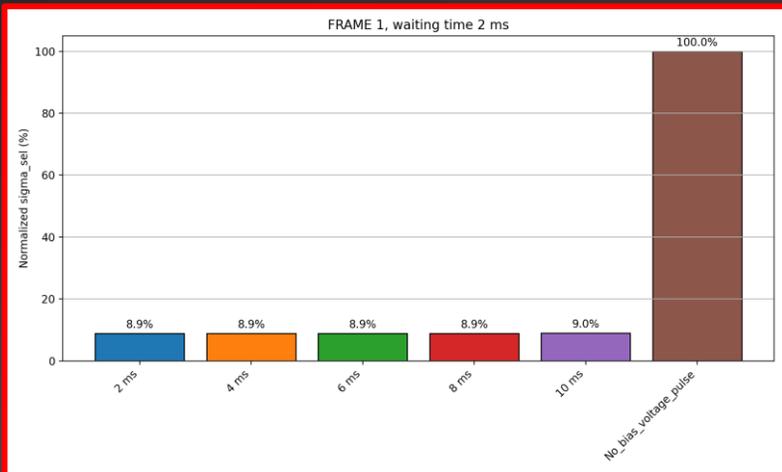
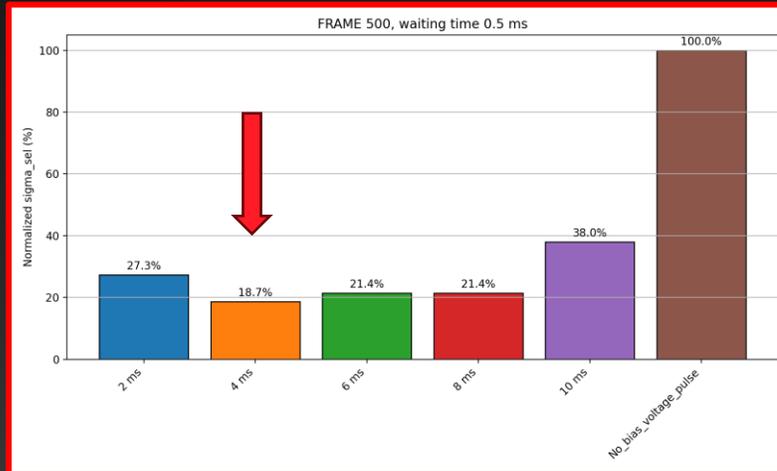
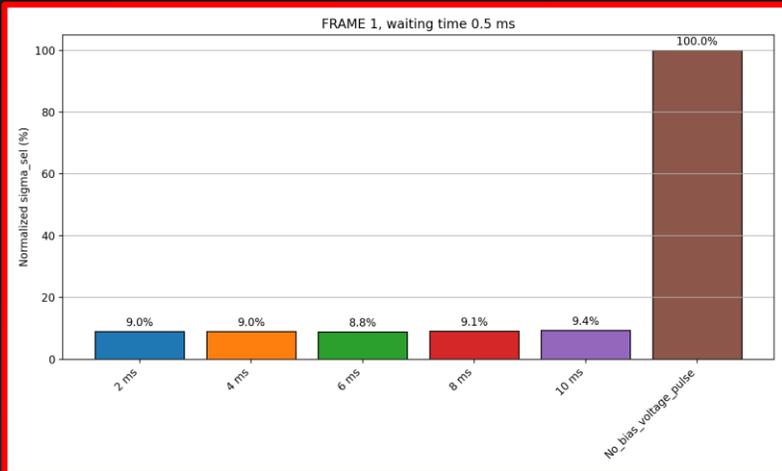
**Without bias refreshing: FRAME 500**



Distribution of the measured intensity values  $\mu$ .



# THE BEST **SHORT** BIAS VOLTAGE PULSE EVALUATION



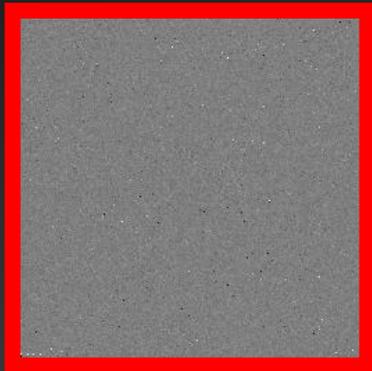
$\sigma$  is calculated only from selected data – specifically, 98% of the sample values that were filtered (most likely by trimming extreme values, i.e., outliers).

The total duration is:  
pulse + waiting time = **5 ms**.

An exposure time is extended by 5 ms before each frame or before a sequence of frames.

# IMAGE COMPARISON: **WITHOUT VS. WITH** BIAS VOLTAGE PULSE REFRESH

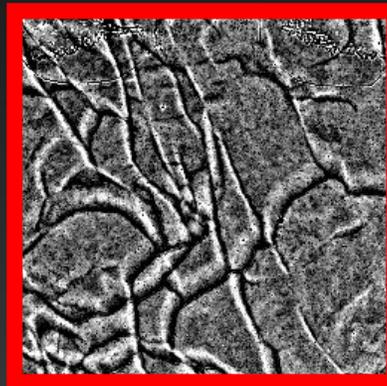
FRAME FF (FLAT FIELD)



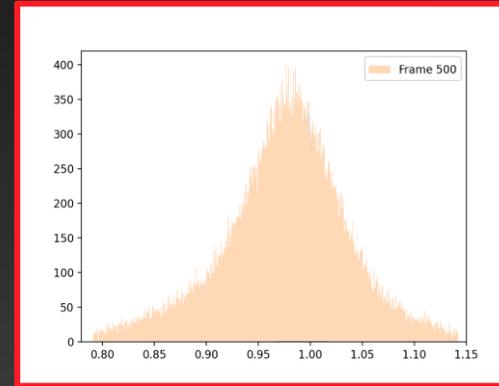
*Without bias refreshing* (arrow pointing up-right)

*With bias refreshing* (arrow pointing down-right)

FRAME 500



Distribution of the measured intensity values  $\mu$ .



Ideally:

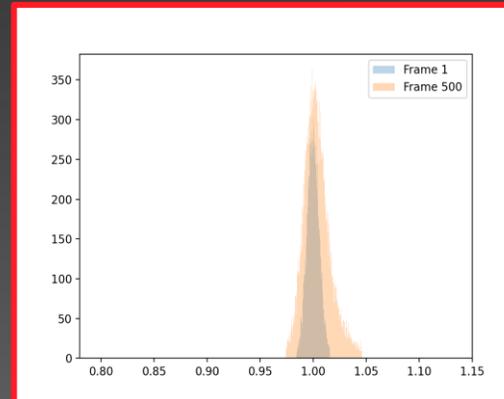
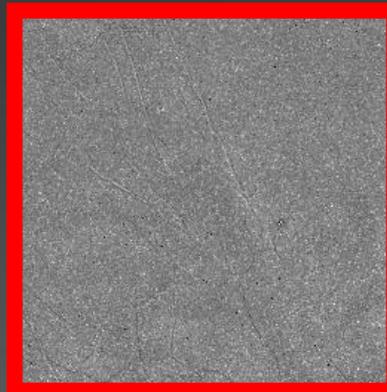
$$\mu_{[x,y]} = \frac{\text{frame}_x[x,y]}{\text{frame}_{FF}[x,y]} = 1$$

*Wider spread!*

← --

**5x WORSE**

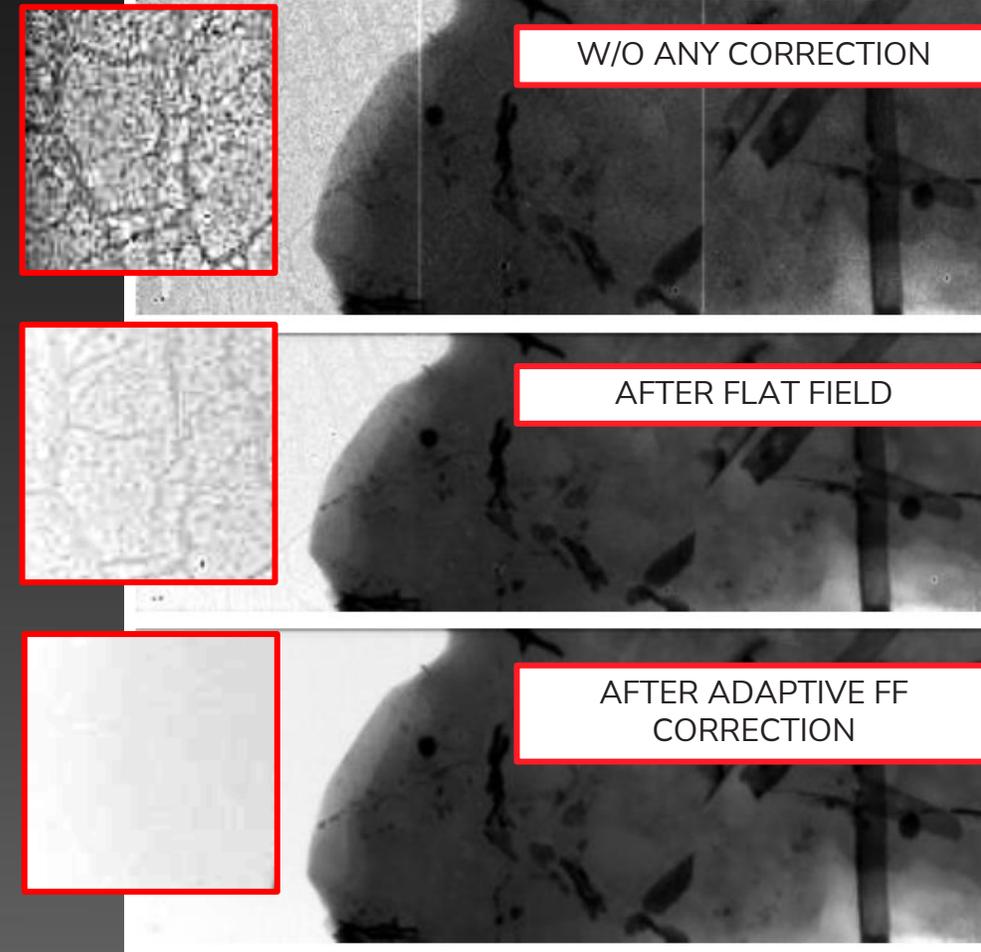
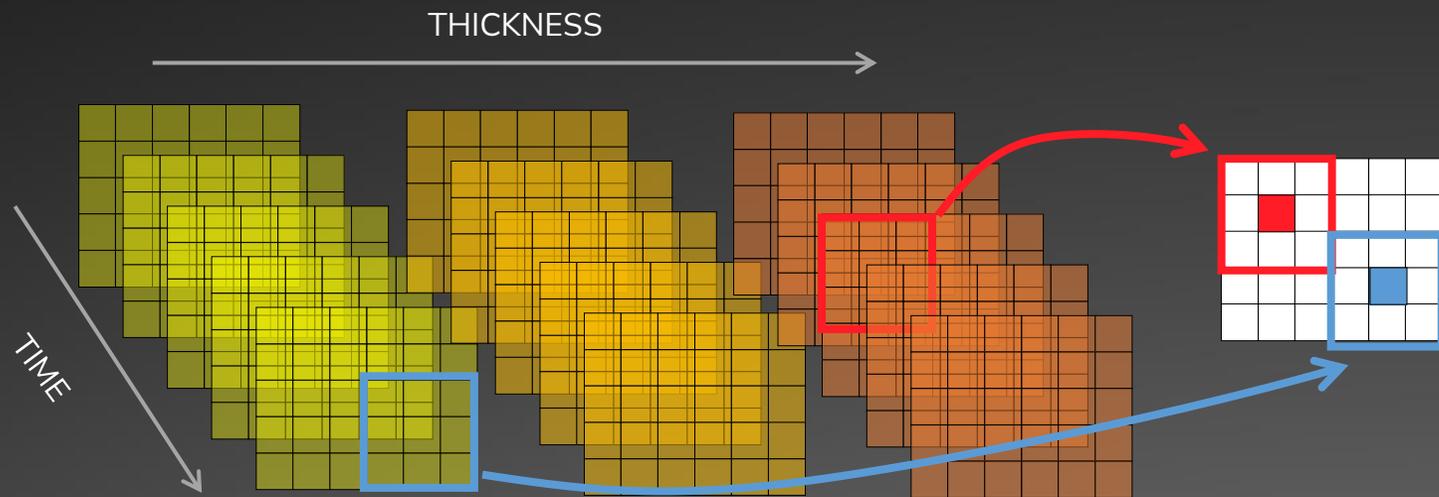
FRAME 500



Bias pulse refresh  
**improves detection stability** of CdTe sensor.

# SOFTWARE SOLUTION

- > **ADAPTIVE FLAT FIELD CORRECTION FUNCTION**
- > IT SELECTS THE **BEST LOCAL** FLAT FIELD FROM A **DATABASE** TO COMPENSATE FOR IMAGE ARTIFACTS
- > COMPUTATIONALLY DEMANDING



# CONCLUSION

## > WIDEPIX 5x5 MPX3

- > Best suited for material analysis, spectral imaging, CT and NDT applications
- > Large area: 70 x 70 mm
- > 1 638 400 pixels

## > Bias pulsing

- > Pulsed bias voltage switching offers a low-cost, easily implementable solution.
- > This technique effectively removes accumulated spatial charge and revitalizes the sensor.
- > The best short bias voltage pulse is 4 ms with waiting time 0.5 ms = 5.35x better detection stability.  
The total duration is: pulse + waiting time = 5 ms.

## > AFF correction

- > Software post-processing – improves the detection stability.

# THANK YOU FOR YOUR ATTENTION

Visit us at booth **ADVACAM**

Interested in **DETECTOR**  
[sales@advacam.cz](mailto:sales@advacam.cz)



Go check our TALKS:

**Cristina Oancea**  
**Carlos Granja**

and POSTERS:

**Kamilla Sabirzyanova**  
**Karolina Melovska**  
**Roman Nebel**  
**Jan Jakubek**

